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## DO NOT ENTER: /K.G.IN THE CLAIMS

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- 1-36 (canceled)
- (currently amended) A <u>compact material</u> comprising:

70 to 97 vol % component A comprising alpha- and beta-SiAION and a and-en amorphous or partially crystalline grain-boundary phase; and

5 to 20 3 to 30 vol.% of component B comprising a hard material is in globular form and an average grain size of 1-5 microns has an average grain size.

wherein when the compact is sintered to form a sintered compact having and has a sintered compact, the sintered compact has surface and a hardness of at least 1550 HV 10 and wherein said compact has an alpha-SiAION gradient which decreases from outside the compact the sintered surface to an inside of the sintered compact:

wherein the alpha SiAION content of the sintered surface ranges has an alpha-SiAION content of up to 100%,

wherein said hard material is <u>SiC</u>, at least one of SiC, Ti(C,N), TiG, TiN, a carbide of an element from one of groups IVb, Vb and VIb of the periodic table, scandium explicitly expenditure oxycarbide or a nitride of an element from one of groups IVa, Vb and VIb of the periodic table, wherein the state of the hard material remains unchanged after sintering;

wherein the content of grain-boundary phase is less than 10 vol.% and comprises phases of aluminum containing melilite or disilicate;

wherein in the sintered state inside of the said sintered compact comprises from 1.5 to 50 vol.% the amount of alpha-SiAION present ranges from 10 to 90 vol.%; and

wherein the amount of beta-SiAION ranges from 10 to 90 vol.%.